

03/11/2009

Features:

- High Reliability
- Base lead provided for conventional transistor biasing
- Rugged package
- Stability over wide temperature
- +1000V electrical isolation
- JANS Level screening available

Applications:

- Eliminate ground loops
- Level shifting
- Line receiver
- Switching power supplies
- Motor control

DESCRIPTION

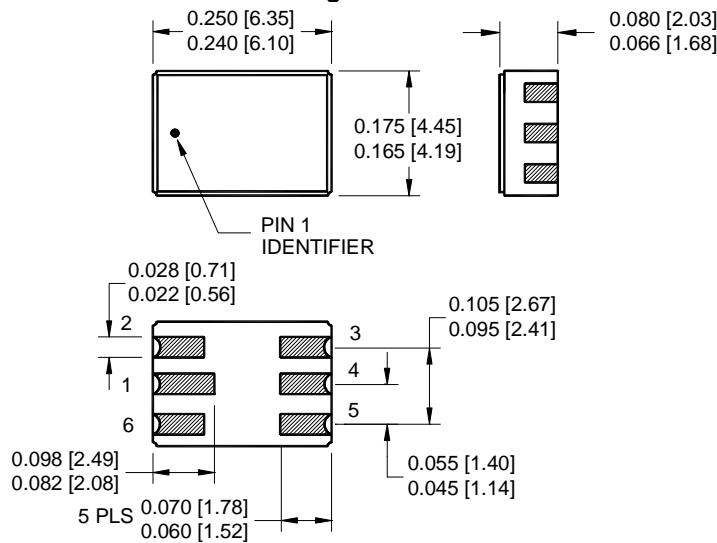
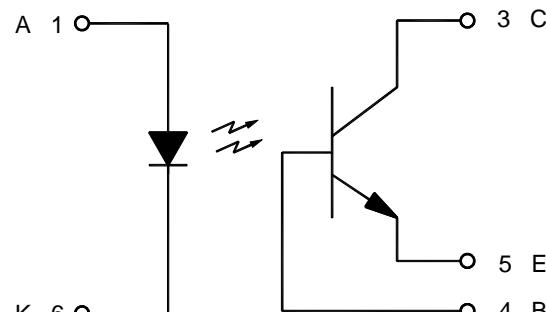
The **66183** is a single channel device electrically similar to the 4N49. This product has been designed to be more tolerant to proton radiation. The 66183 optocoupler is packaged in a hermetically sealed 6 pin leadless chip carrier (LCC). This device can be supplied to customer specifications as well as tested in accordance with MIL-PRF-19500 to Class S level.

ABSOLUTE MAXIMUM RATINGS

| | |
|---|-----------------|
| Input to Output Isolation Voltage | 1 kV |
| Input Diode Continuous Forward Current | 40 mA |
| Peak Forward Input Current (value applies for $t_w \leq 10\mu s$, PRR < 300 pps) | 1 A |
| Reverse Input Voltage | 2 V |
| Input Power Dissipation (Note 1) | 80 mW |
| Emitter-Base Voltage | 7 V |
| Collector-Emitter Voltage (Value applies to emitter-base open-circuited and the input diode equal to zero)..... | 60 V |
| Collector-Base Voltage | 60 V |
| Continuous Collector Current | 50 mA |
| Continuous Transistor Power Dissipation (Note 2) | 300 mW |
| Storage Temperature..... | -65°C to +150°C |
| Operating Free-Air Temperature Range | -55°C to +125°C |
| Lead Solder Temperature (10 seconds max.)..... | 240°C |

Notes:

1. Derate linearly at the rate of 1.33 mW/°C above 65°C case.
2. Derate linearly at the rate of 3 mW/°C above 25°C case.

Package Dimensions**Schematic Diagram**

ALL DIMENSIONS ARE IN INCHES [MILLIMETERS]

66183

PROTON RADIATION TOLERANT 6 PIN LCC OPTOCOUPLER

03/11/2009

ELECTRICAL CHARACTERISTICS

 $T_A = 25^\circ\text{C}$ unless otherwise specified.

| PARAMETER | SYMBOL | MIN | TYP | MAX | UNITS | TEST CONDITIONS | NOTE |
|---|--------|-----|-----|-----|---------------|-----------------------|------|
| Input Diode Static Reverse Current | I_R | | | 10 | μA | $V_R = 2 \text{ V}$ | |
| Input Diode Static Forward Voltage -55°C | V_F | 1.0 | | 2.2 | V | $I_F = 10 \text{ mA}$ | |
| Input Diode Static Forward Voltage $+25^\circ\text{C}$ | V_F | 0.8 | 1.8 | 2.0 | V | $I_F = 10 \text{ mA}$ | |
| Input Diode Static Forward Voltage $+100^\circ\text{C}$ | V_F | 0.8 | | 2.2 | V | $I_F = 10 \text{ mA}$ | |

OUTPUT TRANSISTOR

 $T_A = 25^\circ\text{C}$ unless otherwise specified.

| PARAMETER | SYMBOL | MIN | TYP | MAX | UNITS | TEST CONDITIONS | NOTE |
|--|-----------------------------|-----|-----|------------|---------------------|--|------|
| Collector-Base Breakdown Voltage | $V_{(\text{BR})\text{CBO}}$ | 45 | | | V | $I_C = 100 \mu\text{A}, I_B = 0, I_F = 0$ | |
| Collector-Emitter Breakdown Voltage | $V_{(\text{BR})\text{CEO}}$ | 40 | | | V | $I_C = 1 \text{ mA}, I_B = 0, I_F = 0$ | |
| Emitter-Base Breakdown Voltage | $V_{(\text{BR})\text{EBO}}$ | 7 | | | V | $I_C = 0 \text{ mA}, I_E = 100 \mu\text{A}, I_F = 0$ | |
| Off-State Collector Current $+100^\circ\text{C}$ | I_{CEO} | | | 100 100 | nA μA | $V_{CE} = 20 \text{ V}, I_F = 0 \text{ mA}, I_B = 0$ | |

COUPLED CHARACTERISTICS

 $T_A = 25^\circ\text{C}$ unless otherwise specified.

| PARAMETER | SYMBOL | MIN | TYP | MAX | UNITS | TEST CONDITIONS | NOTE |
|---|----------------------|------|-----|-----|---------------|---|------|
| On State Collector Current | $I_{C(\text{ON})}$ | 2.0 | | | mA | $V_{CE} = 5 \text{ V}, I_F = 1 \text{ mA}, I_B=0$ | |
| On State Collector Current $+100^\circ\text{C}$ | $I_{C(\text{ON})}$ | 2.0 | | | mA | $V_{CE} = 5.0 \text{ V}, I_F = 2 \text{ mA}, I_B=0$ | |
| On State Collector Current -55°C | $I_{C(\text{ON})}$ | 2.8 | | | mA | $V_{CE} = 5 \text{ V}, I_F = 2 \text{ mA}, I_B=0$ | |
| Collector-Emitter Saturation Voltage | $V_{CE(\text{SAT})}$ | | | 0.3 | V | $I_F = 2 \text{ mA}, I_C= 2 \text{ mA}$ | |
| Input to Output Isolation Voltage | V_{I-O} | 1000 | | | V | $I_{I-O} = 100 \text{ nA}$ | 1 |
| Input to Output Capacitance | C_{IO} | | 2.5 | 5 | pF | $f = 1\text{MHz}, V_{I-O} = 1000 \text{ V}$ | 1 |
| Rise Time-Phototransistor Operation | t_r | | 10 | 25 | μs | $V_{CC} = 10 \text{ V}, I_F = 10 \text{ mA}, R_L = 100 \Omega, I_B = 0$ | 2 |
| Fall Time-Phototransistor Operation | t_f | | 10 | 25 | μs | $V_{CC} = 10\text{V}, I_F = 10\text{mA}, R_L = 100 \Omega, I_B = 0$ | 2 |

NOTES:

- These parameters are measured between all phototransistor leads shorted together and with both input diode leads shorted together.
- This parameter must be measured using pulse techniques ($t_W = 100 \mu\text{s}$ duty cycle $\leq 1\%$).

RECOMMENDED OPERATING CONDITIONS:

| PARAMETER | SYMBOL | MIN | MAX | UNITS |
|---------------------------|----------|-----|-----|------------------|
| Input Current, Low Level | I_{FL} | 0 | 90 | μA |
| Input Current, High Level | I_{FH} | 2 | 10 | mA |
| Supply Voltage | V_{CE} | 5 | 10 | V |
| Operating Temperature | T_A | -55 | 100 | $^\circ\text{C}$ |

SELECTION GUIDE

| PART NUMBER | PART DESCRIPTION |
|-------------|--------------------------|
| 66183-001 | Commercial |
| 66183-101 | Screened to JAN level |
| 66183-103 | Screened to JANTX level |
| 66183-105 | Screened to JANTXV level |
| 66183-300 | Screened to JANS level |

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